



40V PNP LOW SATURATION TRANSISTOR IN SOT23

Features

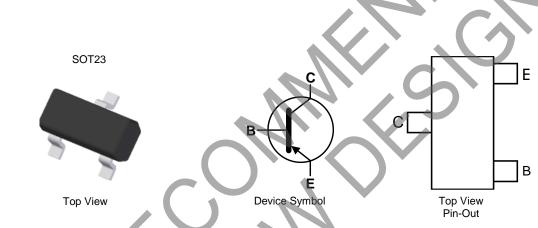
- BV_{CEO} > -40V
- I_C = -2A High Continuous Collector Current
- I_{CM} = -3A Peak Pulse Current
- Low Saturation Voltage -225mV Max @ I_c = -1A
- $R_{CE(SAT)} = 90m\Omega$ at -0.5A for a Low Equivalent On-Resistance
- 730mW Power Dissipation
- Complimentary NPN Type: DSS4240T
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight 0.008 grams (Approximate)

Application

- Gate Driving MOSFETs and IGBTs
- Load Switch
- DC-DC Converters
- Battery Charging



Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DSS5240T-7	NRND (Use ZXTP5240F-7) (Note 5)	ZP2	7	8	3000
DSS5240T-13	NRND (Use ZXTP5240F-7) (Note 5)	ZP2	13	8	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

NRND - Not recommended for new design.

Feb

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Marking Information

						7D2 - Drodu	ot Tuno Mori	king Codo			
				ZP2	Σ	ZP2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)					
Date Code K	еу										
Year	2013	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023
Code	A	В	С	D	E	F	G	Н	I	J	K

Jun

6

Jul

7

Aug

8

Jan

Month

Code

May

5

Apr

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Dec

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Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	Vсво	-40	V
Collector-Emitter Voltage	VCEO	-40	V
Emitter-Base Voltage	Vebo	-5	V
Peak Pulse Collector Current	ICM	-3	А
Continuous Collector Current	Ic	-2	А
Base Current	lв	-300	mA



Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	730	mW
Power Dissipation (Note 7)	PD	600	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	Reja	171	°C/W
Thermal Resistance, Junction to Ambient Air (Note 7)	Reja	209	°C/W
Thermal Resistance, Junction to Lead (Note 8)	Rejl	75	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

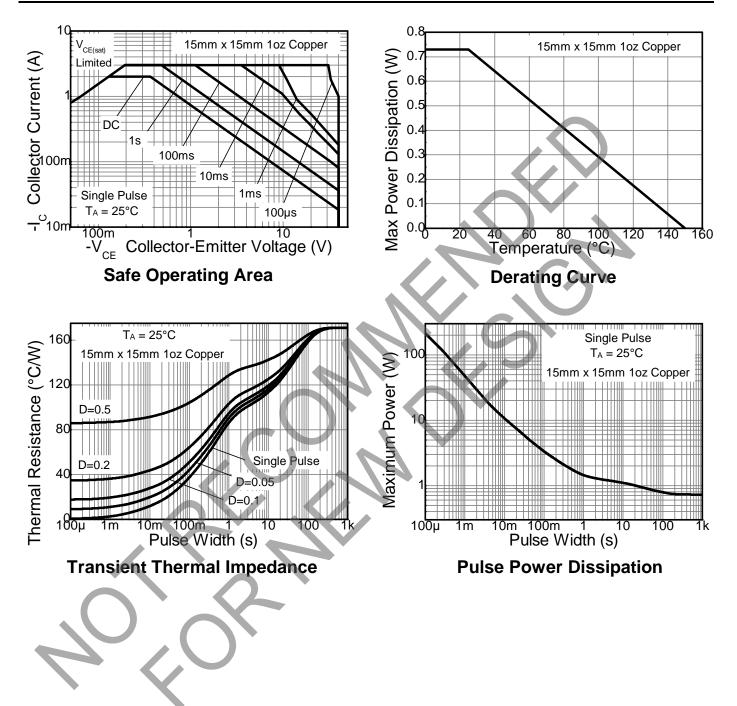
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge—Human Body Model	ESD HBM	4000	V	ЗA
Electrostatic Discharge—Machine Model	ESD MM	400	V	С

6. For a device mounted with the collector lead on 15mm × 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as Note 6, except the device is mounted on minimum recommended pad layout.
8. Thermal resistance from junction to solder-point (at the end of the collector lead).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:



Thermal Characteristics and Derating Information



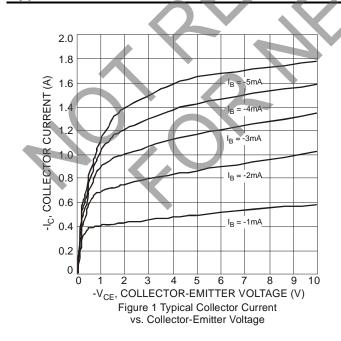


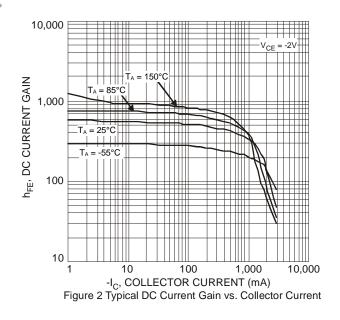
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
OFF CHARACTERISTICS	Symbol	IVIIII	тур	IVIAN	Unit	Test conditions
		40			V	400.4
Collector-Base Breakdown Voltage	ВV _{CBO}	-40	_	_		I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-40	—	—	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BVEBO	-5	_	_	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	Ісво	_	_	-100	nA	$V_{CB} = -30V, I_E = 0$
	ICBO	_	_	-50	μA	$V_{CB} = -30V, I_E = 0, T_A = +150^{\circ}C$
Emitter-Base Cutoff Current	IEBO		-	-100	nA	$V_{EB} = -4V$, $I_C = 0$
ON CHARACTERISTICS (Note 10)	•					
		300	_	_		Vce = -2V, Ic = -0.1A
DC Current Gain		260	_	—	$\mathbf{\nabla}$	Vce = -2V, Ic = -0.5A
	hfe	210		-		Vce = -2V, Ic = -1A
		100		-		$V_{CE} = -2V$, $I_C = -2A$
	Vce(sat)			-100		Ic = -100mA, I _B = -1mA
			-45	-110		Ic = -500mA, I _B = -50mA
Collector-Emitter Saturation Voltage		_		-225	mV	Ic = -750mA, Iв = -15mA
		—		-225		Ic = -1А, Iв = -50mА
		—	—	-350		$I_{C} = -2A, I_{B} = -200mA$
Equivalent On-Resistance	R _{CE(SAT)}		90	220	mΩ	I _C = -500mA, I _B = -50mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	Ŧ	—	-1.1	V	I _C = -2A, I _B = -200mA
Base-Emitter Turn-on Voltage	VBE(ON)	—	—	-0.75	V	Vce = -2V, Ic = -100mA
SMALL SIGNAL CHARACTERISTICS						•
Transition Frequency	fτ	100	F		MHz	V _{CE} = -10V, I _C = -100mA, f = 100MHz
Output Capacitance	Cobo			28	pF	V _{CB} = -10V, f = 1МНz

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

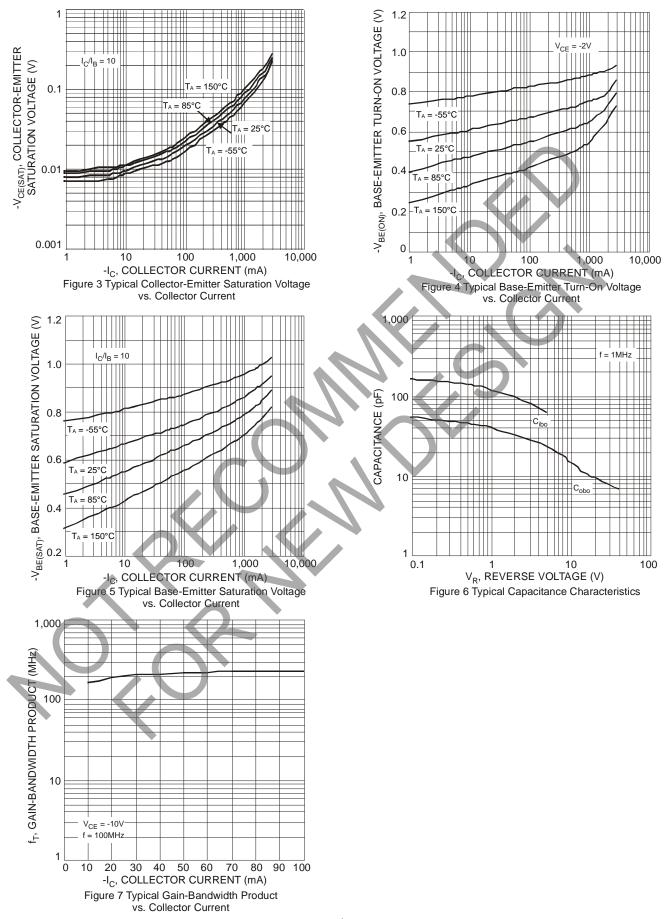






NOT RECOMMENDED FOR NEW DESIGN USE <u>ZXTP5240F</u>

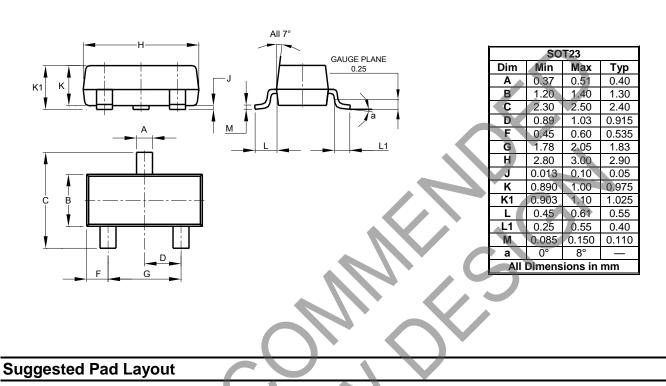
DSS5240T



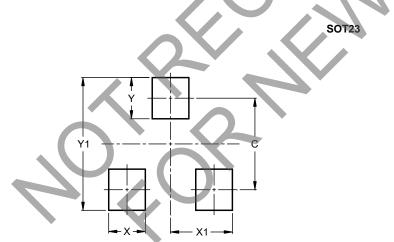


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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